

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

PRELIMINARY AMENDMENT ACCOMPANYING APPLICATION

APPLICANT: Dharam Pal Gosain, et al. ATTY. DOCKET NO. 09792909-5657
SERIAL NO. GROUP ART UNIT:
DATE FILED: July 29, 2003 EXAMINER:
INVENTION: "METHOD OF PRODUCING CRYSTALLINE SEMICONDUCTOR
MATERIAL AND METHOD OF FABRICATING SEMICONDUCTOR
DEVICE"

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

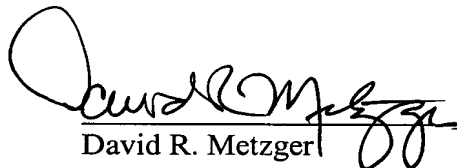
S I R:

Between the title and the heading "Background of the Invention" on page 1, insert the following:

--RELATED APPLICATION DATA

The present application claims priority to Japanese Application(s) No(s). P2002-242614 filed August 22, 2002, which application(s) is/are incorporated herein by reference to the extent permitted by law.--

Respectfully submitted,



(Reg. No. 32,919)

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